

Cite this: *Chem. Sci.*, 2024, 15, 8775

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Metal-free platforms for molecular thin films as high-performance supercapacitors†

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Controlling chemical functionalization and achieving stable electrode–molecule interfaces for high-performance electrochemical energy storage applications remain challenging tasks. Herein, we present a simple, controllable, scalable, and versatile electrochemical modification approach of graphite rods (GRs) extracted from low-cost Eveready cells that were covalently modified with anthracene oligomers. The anthracene oligomers with a total layer thickness of ~24 nm on the GR electrode yield a remarkable specific capacitance of ~670 F g⁻¹ with good galvanostatic charge–discharge cycling stability (10 000) recorded in 1 M H₂SO₄ electrolyte. Such a boost in capacitance is attributed mainly to two contributions: (i) an electrical double-layer at the anthracene oligomer/GR/electrolyte interfaces, and (ii) the proton-coupled electron transfer (PCET) reaction, which ensures a substantial faradaic contribution to the total capacitance. Due to the higher conductivity of the anthracene films, it possesses more azo groups (–N=N–) during the electrochemical growth of the oligomer films compared to pyrene and naphthalene oligomers, which is key to PCET reactions. AC-based electrical studies unravel the in-depth charge interfacial electrical behavior of anthracene-grafted electrodes. Asymmetrical solid-state supercapacitor devices were made using anthracene-modified biomass-derived porous carbon, which showed improved performance with a specific capacitance of ~155 F g⁻¹ at 2 A g⁻¹ with an energy density of 5.8 W h kg⁻¹ at a high-power density of 2010 W kg⁻¹ and powered LED lighting for a longer period. The present work provides a promising metal-free approach in developing organic thin-film hybrid capacitors.

Received 25th January 2024
Accepted 19th April 2024

DOI: 10.1039/d4sc00611a

rsc.li/chemical-science

Introduction

The increasing global population and depletion of fossil fuels have raised significant demands for technological gear, especially portable and lightweight energy storage systems.^{1–6} To meet ever-expanding energy storage requirements, the number of organic supercapacitor (OSC) devices has been expanding, but it is vital to elevate the energy density and power density.^{7–12} Excellent synthetic flexibility, light weight, low production cost, tunable electrical conductivity, porosity, sustainable organic electrodes, and easy fabrication under ambient conditions make organic supercapacitors suitable for advanced technological solutions for storing electrical energy in different forms.^{13–17} Heteroatoms (N, P, O, S), due to their relatively larger

electronegativity than carbon, increase surface wettability, alter the Fermi energy (E_F), and enhance capacitive performance upon functionalization on carbon electrodes.^{18–21} Generally, the energy density of an OSC can be improved either by broadening the operational voltage window (which also depends on the nature of the electrolyte) or by increasing the specific capacitance of the electrode materials by combining electrical double-layer capacitance (EDLC) and pseudocapacitance.^{22–25} Over the last decades, both organic and inorganic “nanomaterials” have played significant roles in electrical energy storage applications.^{26–28} In addition to the advantages of high surface area, the critical size of energy-storing materials shrinks to a nanoscale dimension (~1–100 nm in length); thus, the diffusion length for ions is reduced compared to the bulk, which quickens the charging–discharging process, increases the cycle life, and lowers the operational bias, hence enhancing overall supercapacitor performance.²⁹ Among the promising candidates, graphite rods (GRs) have been extensively exploited in dry cells and electrochemical supercapacitors due to their high double-layer capacitance and lower cost; however, they suffer from low energy density and lower cyclic stability.³⁰

In conjunction with the emergence of these nanostructured carbon materials, there has been a surge of interest in controlling physical and chemical properties through covalent

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† Electronic supplementary information (ESI) available: Synthesis, and characterization of aryl diazoniums, voltammograms of electrochemical reduction, thin film characterization, and additional data on asymmetric supercapacitor devices (PDF). See DOI: <https://doi.org/10.1039/d4sc00611a>

surface modification.^{31–34} Such covalent surface functionalization is a challenging task, and sometimes relies on high-energy reagents and harsh reaction conditions that make uncontrollable and un-reproducible nanostructures.^{35,36} To address this issue, the electrochemical reduction of aryl diazonium is the most efficient approach as it can create strong, stable, robust covalent bonds between the molecule and the working electrode that may be suitable for multi-purpose usage.^{37–41} Though surface modification of carbon materials by spontaneous reduction of diazonium has already been studied in energy storage,^{42,43} the technique does not provide a controlled, homogeneous nanoscale multilayer film and requires a longer time.

We have opted here for a simple, fast-film-forming bottom-up approach to modify graphite rods (GRs) with high surface area and nitrogen-rich graphene structures formed *via* electrochemical reduction of diazonium salts of three different amine compounds, 1-amino anthracene (ANT), naphthalene (NAPH), and pyrene (PYR), and their electrochemical capacitance performances are compared with each molecular layer. The ANT-modified GR oligomer films show high charge storage due to two major contributions: non-faradaic (electrochemical double-layer) and faradaic (interfacial proton-coupled electron transfer). We also reused the used graphite rods extracted from commercially available low-cost Eveready cells (US\$1.5 for 10 cells of 1.5 V) for electrochemical supercapacitor studies upon growing nanoscale molecular films, which also reveal excellent charge storage compared to the unmodified ones. In addition, we fabricated asymmetric supercapacitor devices using ANT-

grafted porous carbon as a positive electrode and porous carbon as a negative electrode, showing a capacitance value of 155 F g^{-1} at 2 A g^{-1} , illustrating the excellent potential of a covalently bonded anthracene oligomer in charge storage. The present study comprises low-cost materials that can be easily scaled up to fabricate high-capacity energy systems for practical applications in molecular energy storage at the nanoscale, so the concept of “waste to energy” could be viable.

Results and discussion

The synthesis and characterization of respective diazonium salts are discussed in ESI (Fig. S1–S3†), and they were used for the growth of molecular layers on graphite rods (GRs) by the electrochemical (E-Chem) reduction method. Fig. 1a shows the potentiostatic cyclic voltammogram (CV) scans (1–20 cycles) of electrochemical grafting of a GR substrate performed in 5 mM of anthracene diazonium salts in acetonitrile recorded at a 100 mV s^{-1} scan rate using 0.1 M *n*-tetrabutyl ammonium perchlorate (TBAP) as a supporting electrolyte. The CV shows the two reduction peaks: a broad irreversible reduction peak at -0.22 V (vs. Ag/AgNO_3) observed during the first scan, indicating the reduction of anthracene diazonium salts (D-ANT); and a higher cathodic peak indicating the formation of ANT layers on the different planes of the GR. Being highly reactive, aryl radicals (generated at the working electrode surface) covalently bonded to the graphite rod and were extended with a repeated number of CV scans, keeping the potential window unchanged (Fig. S4 and S5, Table S1†). Continuous binding of

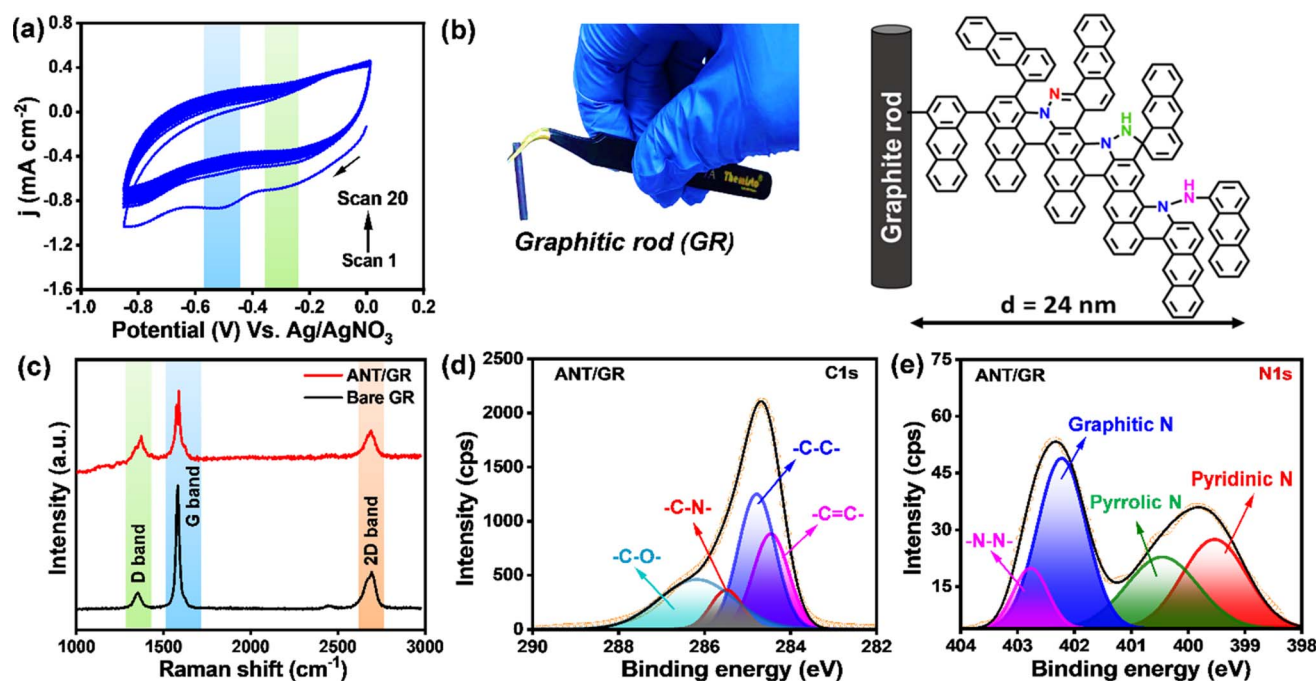


Fig. 1 The formation of electrochemically grafted anthracene oligomeric films, plausible on-surface composition, and spectroscopic characterization. (a) Cyclic voltammograms of E-Chem grafting of anthracene diazonium salts of 5 mM in CH_3CN with 0.1 M TBAP recorded at 100 mV s^{-1} for 20 CV scans. (b) Digital image of graphite rod (GR) on left; on right a schematic illustration of E-Chem-grafted anthracene (ANT) multilayers with different types of nitrogen site: pyridinic N (red), pyrrolic N (green), graphitic N (blue), N–N (sky blue) on a graphite rod (GR) electrode. (c) Raman spectra of bare GR and ANT/GR. (d) Deconvoluted and fitted XPS spectra of C1s of ANT/GR, and (e) N1s of ANT/GR.

(for instance, ANT) radicals maintains the growth of anthracene molecular layers along with azo groups ($-\text{N}=\text{N}-$) as bridges. However, though there have been previous studies on E-Chem-grafted molecular layers utilized for hybrid supercapacitors, none of the work highlighted such unexpected azo formation during E-Chem grafting.³⁹ Non-radical formation of azo bridges between layers is one of the main assumptions to explain layer growth other than radical polymerization. A proposed schematic structure of an ANT thin film with different types of nitrogen on the GR electrode is shown in Fig. 1b with a digital image of a GR. Atomic force microscopy (AFM) measurements were used to evaluate the thickness of the molecular films by scratching the ANT films with a sharp needle, and it was found to be 23 ± 0.8 nm using depth analysis (Fig. S6 and S7†). The baseline-corrected UV-vis spectra of the thin film are shown in Fig. S8†. The obtained spectra for NAPH and PYR thin films show strong peaks at $\lambda = 344$ nm and $\lambda = 365$ nm due to a π to π^* transition. However, the ANT oligomer film shows a broad signal in the visible region, which is red-shifted (n to π^* transition) due to the formation of extended conjugation in the ANT film, offering a lower band gap of 1.7 eV compared to NAPH and PYR thin films (Tables S2 and S3†).

The amorphous nature of the ANT films grown on GR was confirmed by X-ray diffraction (XRD) studies (Fig. S9 and S10†). The diffraction peaks at 2θ values of 26.5° , 42.4° , 44.5° , 54.5° , 77.5° , and 83.6° correspond to the (002), (100), (101), (004), (103), and (110) planes of hexagonal graphite with $P6_3/mmc$ space group (JCPDS 00-008-0415) for all the films, including bare GR. However, no significant change was observed after grafting, possibly due to the lower surface coverage of ANT layers on the GR surface. In addition, the field-emission scanning electron microscopy (FE-SEM) image of bare GR shows micrometer-sized flake-like structures (Fig. S11a†), whereas, after grafting with ANT, the FE-SEM image reveals globular structures with an increase in roughness, suggesting the growth of ANT layers and filling of voids on the graphite surface (Fig. S11b†). The Raman spectra of bare GR and ANT/GR show a strong D-band at 1351 cm^{-1} , a G-band at around 1583 cm^{-1} , and a strong 2D-band around 2705 cm^{-1} (Fig. 1c and S12†). The D-band is observed due to the breathing mode of k -point phonons of A_{1g} symmetry of the porous carbon, which also reveals the presence of defect sites, impurities, and disorder in the structure.⁴⁴ The I_D/I_G ratios were 0.12 and 0.36 for bare GR and ANT/GR, respectively, indicating increased disorder with the ANT oligomer films, as is apparent in the FE-SEM image. The G-band represents the E_{2g} phonon of sp^2 carbon atoms and corresponds to the ordered sp^2 -hybridized graphene network.⁴⁵ The 2D peak was observed at about 2700 cm^{-1} , caused by the second-order vibration of two phonons with opposite wave-vectors. The X-ray photoelectron spectra (XPS) of the C1s in bare GR were deconvoluted into three peaks at binding energies of 284.5 eV, 284.9 eV, and 285.9 eV corresponding to sp^2 -hybridized $\text{C}=\text{C}$, sp^3 -hybridized $\text{C}-\text{C}$, and $\text{C}-\text{O}$ components, respectively^{46–48} (Fig. S13 and S14†). In contrast, the expanded and deconvoluted XPS spectra of C1s of ANT/GR show four contributions at 284.4 eV, 284.7 eV, 285.5 eV, and 286.1 eV for $\text{C}=\text{C}$, $\text{C}-\text{C}$, $\text{C}-\text{N}$, and $\text{C}-\text{O}$, respectively (Fig. 1d), which are well

correlated with previous reports.^{49–51} Interestingly, in ANT/GR, two broad peaks in the range of 398 eV to 402 eV were obtained, which were further deconvoluted into four peaks at 399.5 eV, 400.5 eV, 402.2 eV, and 402.8 eV, suggesting the presence of four types of N (as illustrated in Fig. 1b), pyridinic N, pyrolytic N, graphitic N, and N–N, respectively, but they were absent in bare GR, supporting the presence of nitrogen-comprising ANT layers on the GR surface (Fig. 1e and S15†).^{46,52} The binding energies of elements in both bare GR and ANT/GR electrodes are given in Table S4.† The presence of hydrophilic nitrogen elements was further supported by static water-contact angle studies. The ANT/GR surface shows a hydrophilic surface with a reduced water contact angle of $63.5^\circ \pm 0.77^\circ$ compared to bare GR with a water contact angle of $127^\circ \pm 0.02^\circ$ (Fig. S16, Table S5†). This observation unequivocally suggests the formation of oligomer films on GR surfaces.

The BET surface area was evaluated by measuring the N_2 adsorption-desorption isotherm, and the pore volume was calculated using the DFT simulation. The isotherms were of Type III, indicating multilayer formation where the mesopores and macropores were not filled completely. The adsorption-desorption hysteresis was H3-type, suggesting a plate-like structure of bare GR and ANT/GR, which is also visible from the FE-SEM microscopic images, where we can see the existence of ink-bottle and slit-shaped pores (Fig. S17†). The bare GR shows a relatively low specific surface area of $2.05\text{ m}^2\text{ g}^{-1}$ and a pore volume of $0.004\text{ cm}^3\text{ g}^{-1}$, whereas after grafting ANT films, both surface area and pore volume increased to $2.41\text{ m}^2\text{ g}^{-1}$ and $0.006\text{ cm}^3\text{ g}^{-1}$. A 20% increase in surface area and pore volume is potentially due to the disordered growth of ANT layers on GR, as evidenced in the FE-SEM images and Raman spectra. Fig. S18† presents mesopores, as most of the pore size distribution lies in the 10–50 nm range, with a slight contribution from macropores.

Based on the experimental observations, we considered four different structural possibilities of ANT films, where azo-functionalized ANT was separately grafted on GR/N-GR *via* chemisorption through C–C or C–N coupling (Fig. S19–S21†). Geometric optimization was carried out using the density functional theory (DFT) framework with VASP code,^{53,54} where the azo-functionalized anthracene oligomeric molecules were optimized on an 8×8 supercell of hexagonal 2D monolayered graphene. The DFT computed geometry shows that the azo-functionalized anthracene oligomeric structures are intact on the GR/N-GR sheet (Fig. S22†). Upon grafting, the hybridization of the C/N of the GR/N-GR sheet changes from sp^2 to sp^3 , which pushes the C/N atoms out of the plane of the sheet. The charge difference density plots show an electron-rich C/N atom of the GR/N-GR sheet with a charge accumulation on the C–C and C–N bonds (Fig. 2a and b). To gain better insight into the nature of the interaction, we undertook energy decomposition analysis⁵⁵ using a cluster model comprised of 245 atoms where terminal carbon atoms were saturated with hydrogens. For both the studied cluster models, we observed that the C–C and C–N bond formations stabilize with intermolecular interaction energies of $\sim 54\text{ kcal mol}^{-1}$ and $\sim 72\text{ kcal mol}^{-1}$ for 1@N-GR and 1@GR, respectively. The orbital and electrostatic interactions are the



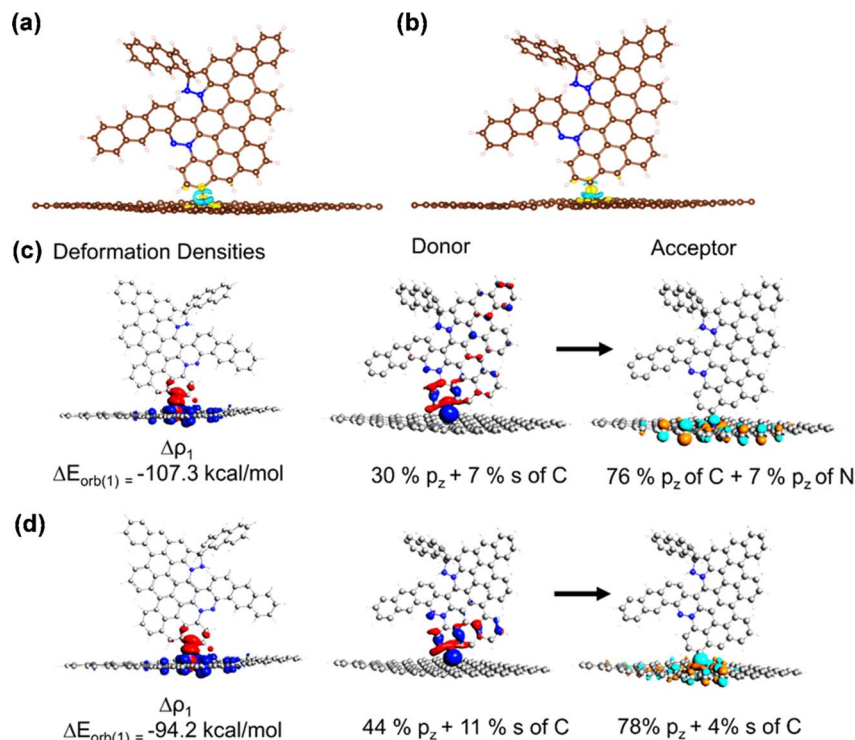


Fig. 2 Computational studies on azo-functionalized anthracene grafted on GR/N-GR through chemisorption. DFT computed charge difference density plots for (a) 1@N-GR and (b) 1@GR (iso-value 0.007 a.u.). The yellow region shows charge accumulation, whereas blue shows charge depletion. Colour code: C – brown, H – white, N – blue. ETS-NOCV computed electron deformation density for (c) 1@N-GR and (d) 1@GR (iso-value – 0.001 a.u.). The red and blue contours correspond to the accumulation and depletion of electron density, respectively. Direction of the negative charge flow: red → blue.

major contributors to the total intermolecular interaction energy, with the former being relatively dominant. The sizeable electrostatic interaction in 1@N-GR arises from the large negative Mulliken charge on the N atom of N-GR compared to the C atom of GR. Electron deformation density analysis⁵⁵ shows electron flow from the GR/N-GR sheet to the $2p_z$ anti-bonding orbital of the C–C and C–N bonds, which agrees with the CDD analysis of the periodic structure (Fig. 2c and d, S23 and S24, Table S6†). Our computational results demonstrate that azo-functionalized anthracene oligomeric structures are stabilized on graphene/N-doped graphene, which agrees with experimental observations where ANT films are created *via* covalent bond formation.

Next, the ANT/GR electrode was examined for electrochemical supercapacitor applications (a set-up is shown in Fig. 3a). Fig. 3b shows the cyclic voltammograms (CVs) of bare GR and ANT-modified GR recorded in 1 M H_2SO_4 (three-electrode set-up) at 100 mV s^{-1} and 500 mV s^{-1} scan rates (CVs at other scan rates are shown in Fig. S25a and b†). In contrast to bare GR, the ANT/GR electrodes exhibited a well-defined faradaic feature at about +0.31 V (vs. Ag/AgCl) which can be ascribed to interfacial proton-coupled electron transfer (PCET). An increase in the peak-to-peak separation (ΔE_p) was observed as a function of the scan rate, which was used to determine the apparent rate constant, k_{app} , using the Laviron formalism.⁵⁶ At slower scan rates ($\leq 100 \text{ mV s}^{-1}$), ΔE_p remains

constant in the 50–53 mV range but increases at higher scan rates. Fig. S26† shows the trumpet plot for ANT/GR in 1 M H_2SO_4 solution, allowing the charge transfer coefficient, α , and $1 - \alpha$ to be calculated at 0.35 and 0.36, respectively. The k_{app} of the anodic reaction and the cathodic reaction were calculated as 14.9 ± 0.8 and $14.0 \pm 0.6 \text{ s}^{-1}$, respectively, indicative of a fast charge transfer process (see ESI† for detailed calculations) and nearly 10 times higher than those of the self-assembled organic redox-active species.^{57,58} Moreover, the reversible redox behavior of bare GR and ANT/GR electrodes was observed in the presence of ferrocene, a well-known redox marker⁵⁹ (Fig. S27†). The diffusion coefficient, D , related to the electrochemical nature of the charge transfer process, was deduced using the well-known Randles–Ševčík eqn (i).⁶⁰

$$i_p = 2.695 \times 10^5 A D^{1/2} n^{3/2} \nu^{1/2} C \quad (\text{i})$$

The anodic and cathodic currents were plotted as a function of the square root of the scan rate (i_a vs. $\nu^{1/2}$) (Fig. S28†). From the slope of the plot, the diffusion coefficients (D) of ferrocene were calculated to be $4.2 \pm 0.18 \times 10^{-5} \text{ cm}^2 \text{ s}^{-1}$ for bare GR and $5.6 \pm 0.44 \times 10^{-5} \text{ cm}^2 \text{ s}^{-1}$ for ANT/GR electrodes, ensuring the facile formation of ferrocene–ferricinium species at the electrode surfaces.⁵⁹ The CVs of ANT-modified GR were recorded with varying electrolyte temperatures, and the activation energy (E_a) was calculated to be $10.5 (\pm 0.4) \text{ kJ mol}^{-1}$



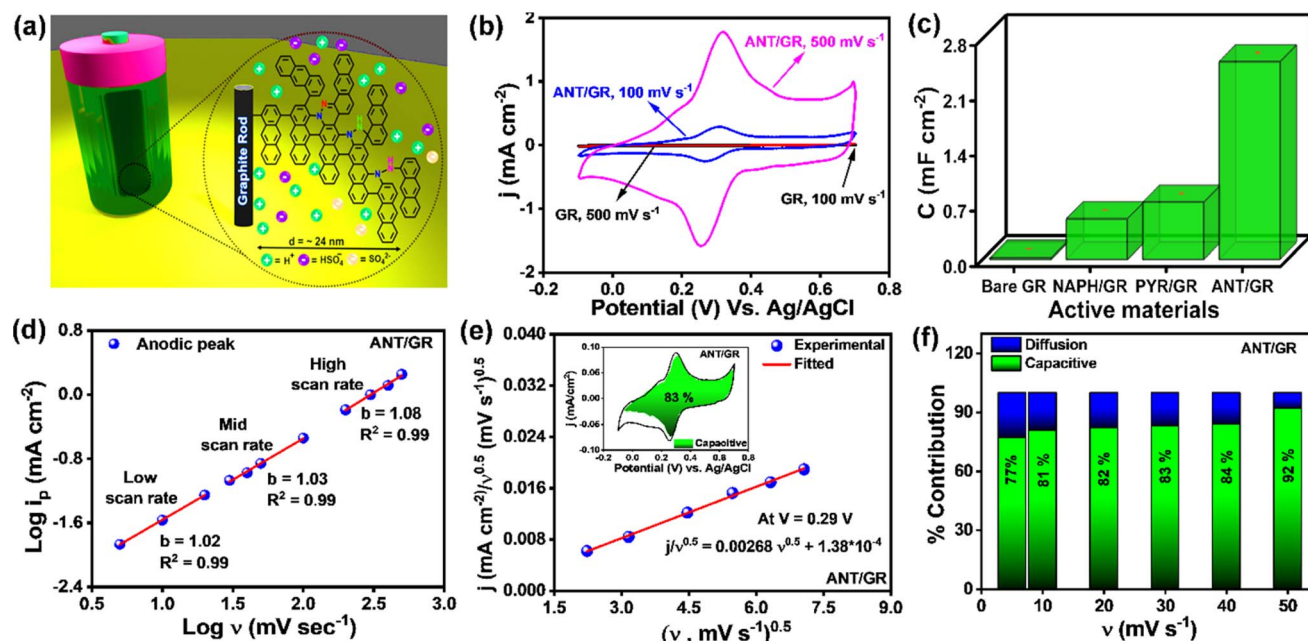


Fig. 3 Electrochemical supercapacitor analysis of oligomeric films E-Chem grafted on a graphite rod. (a) Schematic showing E-Chem-grafted anthracene (ANT) multilayers with different types of nitrogen site on a graphite rod (GR) electrode in H_2SO_4 electrolyte. (b) Comparison of cyclic voltammograms of bare GR, ANT/GR in 1 M H_2SO_4 at 100 mV s^{-1} and 500 mV s^{-1} scan rates. (c) Bar diagram representing total areal capacitance of bare and modified electrodes calculated from CV at 500 mV s^{-1} (with error bars in red). (d) Plots of $\log(i_p)$ vs. $\log(\nu)$ from low to high scan rates for the ANT/GR electrode in the anodic regime. (e) Plot of j (mA cm^{-2})/ $\nu^{0.5}$ (mV s^{-1}) $^{0.5}$ vs. $(\nu, \text{mV s}^{-1})^{0.5}$ at 0.29 V; inset shows CV at 30 mV s^{-1} scan rate illustrating capacitive (green) and diffusion-controlled (white) charge storage process. (f) Pseudocapacitive contributions of ANT/GR at different scan rates.

(Fig. S29[†]). The ANT-grafted GR electrode showed excellent thermal stability when heated at 75 °C for 12 h (Fig. S30[†]). The total capacitance was further determined and compared for both systems by integrating the surface area obtained from the CVs in 1 M H_2SO_4 electrolyte and compared with naphthalene (NAPH) and pyrene (PYR) films (Fig. S31–S34[†]). Bare GR shows an electrochemical double-layer capacitance (EDLC) of $24 \pm 1.36 \mu\text{F cm}^{-2}$ measured at a scan rate of 500 mV s^{-1} , which agrees well with that of typical carbon materials.⁶¹ However, the ANT/GR electrode exhibits higher total areal capacitance with a well-defined faradaic feature at ~ 0.31 V (vs. Ag/AgCl), illustrating the pseudocapacitive behavior of the interface. As confirmed by the XPS spectra, nitrogen from azo groups creates several electroactive sites for pseudocapacitive reactions and PCET in response to electrochemical bias. A bar diagram is also shown in Fig. 3c to compare the total areal capacitance of all modified active electrodes at a 500 mV s^{-1} scan rate, showing the huge increase in the capacitance for the ANT/GR electrode in comparison to pyrene and naphthalene oligomeric films. The capacitance in the common metric of F g^{-1} was also evaluated for the ANT/GR electrode using the theoretical mass loading of the ANT film. Since it is challenging to accurately weigh the mass of the nanoscale-grown film on the GR surface experimentally, we considered the theoretical mass loading for the specific capacitance calculations (see ESI section 16[†] for detailed estimation). A specific capacitance of $687 \pm 37 \text{ F g}^{-1}$ was calculated from the integrated area between -0.1 V and 0.7 V for the ANT/GR electrode

at 500 mV s^{-1} scan rate; here, g_{film} indicates the theoretical mass of the ANT film (see ESI section 16[†]). So far, commercially available carbon-based supercapacitors are in the range of 60–100 F g^{-1} , thus a capacitance of $\sim 687 \text{ F g}^{-1}$ for such a nanoscale-grown molecular film is quite notable. Generally, the total capacitance can be divided into two regimes: (i) EDLC and (ii) the faradaic reaction of the active material. However, not all faradaic reactions are pseudocapacitive in nature. A few are controlled by ion diffusion in the active electrode material, including in the electrolytes.⁶² Hence, it is necessary to evaluate the dominant faradaic capacitive and non-capacitive contributions to provide an adequate explanation of the working performance of the active electrode. As shown in eqn (ii), a power-law relationship can be used to distinguish the dominant charge storage process, where i is current at a particular voltage, ν is scan rate, and a and b are constants.⁶³ The measured current is fitted linearly with the $\log(i)$ vs. $\log(\nu)$ plot, providing the b value from the slope. A value of $b = 0.5$ suggests a direct relation between the current and the square root of the scan rate and follows the traditional diffusion-controlled approach. In contrast, $b = 1$ implies a direct relation between the current and the scan rate, which is the hallmark of capacitor-like charge storage behavior.⁶³ CVs from low to high scan rates were used to calculate b values at the maxima in anodic (Fig. 3d) and cathodic regimes (Fig. S35[†]). The linear fit in all three regions displayed a and b values close to 1, indicating that the dominant charge transport mechanism in the ANT/GR electrode is capacitor-like.

$$i(\nu) = a\nu^b \quad (\text{ii})$$

The capacitive contribution to the total current was further evaluated using the Dunn equation, shown below in eqn (iii), where i is the current at a fixed potential, and $k_1\nu$ and $k_2\nu^{0.5}$ relate to capacitive and diffusion contributions to the total current.^{63,64}

$$i(\nu) = k_1\nu + k_2\nu^{0.5} \quad (\text{iii})$$

The value of k_1 was calculated using the above equation at slow scan rates (5 mV s^{-1} to 50 mV s^{-1}), and an 83% capacitive contribution was obtained at a 30 mV s^{-1} scan rate, as shown in Fig. 3e. The capacitive contribution was also calculated at different scan rates. With increasing scan rate, the percentage of capacitive contribution also increases due to the slow diffusion of ions (Fig. 3f). The high capacitive contribution further claimed the fast redox reaction of ANT/GR electrodes, which is highly desirable for pseudocapacitive materials.

Moreover, the capacitance performances were also evaluated by galvanostatic charge/discharge (GCD) cycling over potential ranges of -0.1 V (vs. Ag/AgCl) to $+0.7 \text{ V}$ (vs. Ag/AgCl) at $30 \mu\text{A cm}^{-2}$ for 10 cycles. Bare GR demonstrated a symmetrical and nearly triangular-shaped charge/discharge cycle, clearly indicating the EDLC feature (Fig. 4a). In contrast, a significant change in shape with a negligible potential drop, V_{drop} (equivalent series resistance/ESR of $0.98 \pm 0.02 \text{ m}\Omega \text{ cm}^2$ (Fig. 4b and c)), was observed in ANT/GR, which is the combined EDLC and faradaic contribution (PCET to nitrogen) in the capacitance, as depicted in Fig. 3b. The duration of charging/discharging also

increased after ANT grafting, attributed to the faradaic process. A single charge/discharge cycle is shown in ESI,† illustrating different charge/discharge timescales before and after modification (Fig. S36†). The ANT/GR electrode showed the highest areal capacitance of $\sim 11 \text{ mF cm}^{-2}$ and specific capacitance of $\sim 2900 \text{ F g}^{-1}$ at a lower current density of $10 \mu\text{A cm}^{-2}$, which decreased with increasing applied current density (Fig. 4d and e). However, this value differs from the CV measurements, because the charging/discharging current in the CVs was much higher than in the GCD measurements. The cycle life of ANT/GR was determined by performing 10^4 GCD cycles at an applied current density of 1 mA cm^{-2} (Fig. S37†). It is noteworthy that ANT/GR exhibited excellent cycling performance up to 10^4 GCD cycles and could hold larger charges for a longer time (Fig. 4f). ANT/GR shows increased areal capacitance with the number of GCD cycles, while the coulombic efficiency remains unchanged ($\sim 99\text{--}97\%$) (Fig. S38†).

A gradual increase in capacitance value was observed with increasing GCD cycling. A similar increment in the enclosed area in CV further supports an increment in capacitance (Fig. S39a†). To understand this gradual increase in capacitance value, we performed various studies after 10^4 GCD cycles. The FE-SEM image after 10^4 GCD cycles shows a sponge-like morphology, illustrating the creation of additional active sites for ion adsorption/desorption; hence, a higher EDLC contribution can be anticipated (Fig. S39b†). Also, BET analysis revealed a 179% increase in surface area after 10^4 GCD cycles (Fig. S39c and d†). With an increase in the number of GCD cycles, we observed surface opening in the graphite surfaces

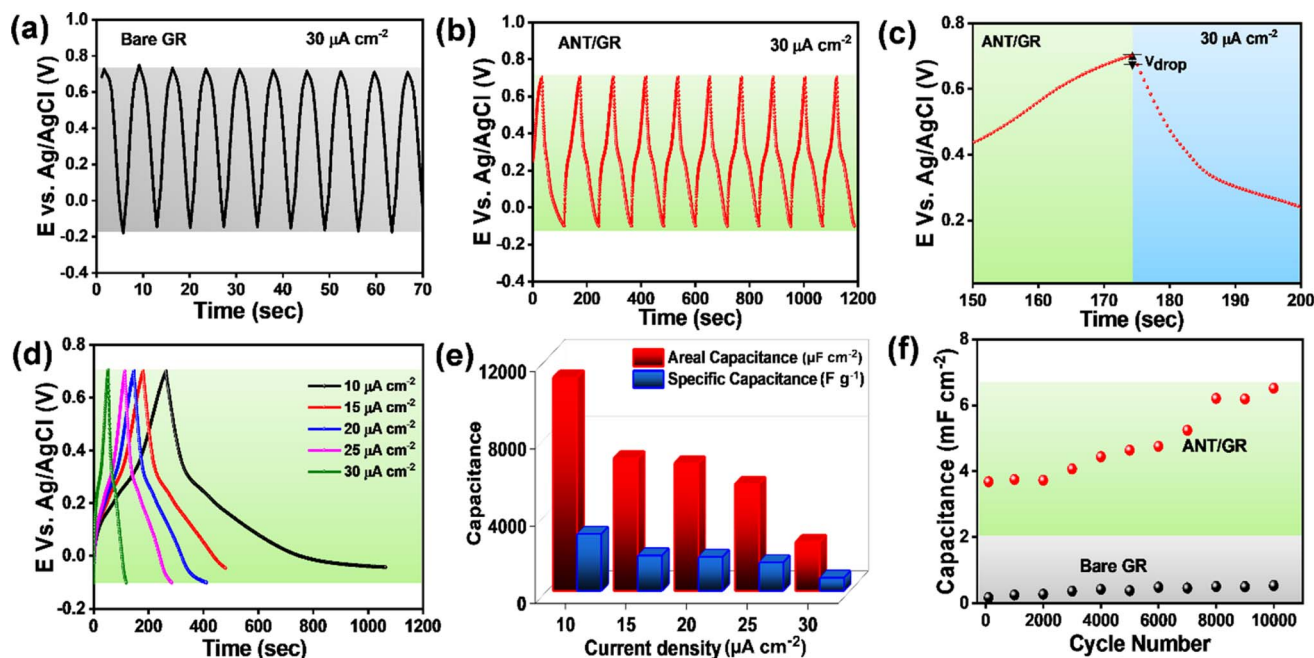


Fig. 4 Galvanostatic charging/discharging analysis of anthracene oligomeric films at different current densities, and cycle numbers. Galvanostatic charging/discharging (GCD) curve of (a) bare GR and (b) ANT/GR at $30 \mu\text{A cm}^{-2}$. (c) A single GCD cycle of ANT/GR at $30 \mu\text{A cm}^{-2}$ showing negligible potential drop, V_{drop} . (d) GCD plot of ANT/GR at different applied current densities. (e) Corresponding capacitance values at different current densities. (f) Cycling performance of bare GR at an applied current density of 0.1 mA cm^{-2} and ANT/GR at 1 mA cm^{-2} ; to ensure the experiment time was the same for bare GR and ANT/GR, 0.1 mA cm^{-2} current density was applied.

taking place, which provides an additional surface area in the electrode and assists in the gradual increase in capacitance with EDLC the dominant contribution. We did not observe any significant change in the XRD peak intensity, and no new peak after GCD cycling was observed; hence, the possibility of forming another carbon-based structure like graphene or graphene oxide can be ruled out (Fig. S39e†). The I_D/I_G ratio in the Raman spectrum after GCD cycling was 0.34, slightly lower than that of ANT/GR ($I_D/I_G = 0.36$). A slight decrease in the I_D/I_G ratio may be due to an increased graphite surface area due to surface opening during charging/discharging (Fig. S39f†). Also, the N1s XPS spectra after 10^4 GCD cycles revealed the presence of four types of N: pyridinic N (399.5 eV), pyrolytic N (400.0 eV), graphitic N (401.1 eV), and N-N (402.2 eV), with a slight shift in binding energy from pristine ANT/GR. The results confirmed the integrity and stability of ANT films on the GR surface even after 10^4 GCD cycles, which is certainly due to the strong covalent bonding of ANT to the GR surface (Fig. S40†).

Both the CV and GCD techniques are based on DC-based measurements producing either total current or charges in the system, but they do not forecast frequency response, which is crucial for understanding capacitance performance.⁶⁵ Electrochemical impedance spectra obtained in frequency ranges of 10^{-1} to 10^4 Hz for a bare GR electrode and ANT-modified GR electrode before and after 10^4 GCD cycles are presented in Fig. 5. As expected, the bare electrode shows a constant phase element (CPE) (Fig. 5a) that can be better evidenced by the variation in the imaginary part of the impedance as a function of frequency (Fig. 5b).^{66,67} The slope of the curve is the opposite of the coefficient α of the CPE, whereas the determination of Q is possible from eqn (iv):

$$Q = \frac{-1}{Z_j \times (2\pi f)^\alpha} \times \sin\left(\frac{\alpha\pi}{2}\right) \quad (\text{iv})$$

Then, using the Brug formula,^{68,69} $C = Q^{1/\alpha} R_e^{(1-\alpha)/\alpha}$ in which R_e is the electrolyte resistance, a capacitance of about $1.5 \mu\text{F cm}^{-2}$ can be obtained. Such a value is consistent with a double layer formed at a graphite/electrolyte interface.⁷⁰ On the ANT-modified electrode (Fig. 5c), the shape of the impedance diagram remains unchanged, but the modulus is 10 times smaller, corresponding to an increase in the active surface area. Graphical analysis of this diagram is also consistent with capacitive behavior (Fig. 5d). After 10^4 GCD cycles, the shape of the impedance diagram clearly shows two linear domains corresponding to two types of CPE behavior, whereas the modulus is about 100 times smaller than that measured on the as-prepared electrode (Fig. 5e). This can be explained by a rearrangement of the layer upon cycling and the formation of small pores in the thin film. This is confirmed by the graphical analysis presented in Fig. 5f, which distinctly exhibits two different linear domains for the determination of α , one in the high frequencies with a value close to 0.66 and a second one in the lowest frequency domain with a value close to 0.81. Such a value in high frequency is consistent with a porous system. However, it is not possible to go further in the determination of the size, depth, and diameter of the

pores because all these parameters are linked.⁷¹ Moreover, analysis of the graphically determined value of the Q parameter (Fig. 5f) shows that the capacitance value is in the range of a few mF cm^{-2} , in agreement with the CV and GCD results, but the change in the active surface during cycling does not allow better quantitative analysis. Finally, these diagrams were obtained at the faradaic process at +0.3 V (vs. Ag/AgCl), which is superimposed on the capacitive response. Extrapolation of the diagram presented in Fig. 5e allows us to determine a charge transfer resistance of about 200Ω . This value can only be obtained at very low frequencies because of the parallel behavior of resistance with a double-layer capacitance of an electrode of a very high value. Furthermore, if we relate this value to a unit area, the analysis of impedance diagrams shows that there is an increase of a factor of 100 to 1000 between a bare electrode and an electrode after cycling. We deduce that the charge transfer resistance is small, which is characteristic of a Nernstian system, again in agreement with the cyclic voltammetry results. The fitted electrochemical parameters are shown in Fig. S41 and Table S7.†

Additionally, we have directly isolated graphited rods from a discharged Eveready dry cell (EV-GR, AA, 1.5 V) in order to recycle and increase the charge-storing efficiency of discharged graphite electrodes. We modified EV-GR *via* electrochemical grafting using anthracene diazonium salts (Fig. S42 and S43a†). Compared to unmodified EV-GR, ANT-modified EV-GR shows a faradaic redox feature at $\sim +0.36$ V (vs. Ag/AgCl in 1 M H_2SO_4) and exhibits a seven-fold increase in total areal capacitance. A large increase in capacitance was observed with covalent ANT modifications calculated from GCD in -0.1 V to $+0.7$ V (vs. Ag/AgCl) at an applied current density of $30 \mu\text{A cm}^{-2}$ for nine cycles from $615 \pm 7.5 \mu\text{F cm}^{-2}$ to $9761 \pm 44 \mu\text{F cm}^{-2}$ (Fig. S43b–d†). The electrical conductivity of bare and modified GRs was also tested using two probe contact methods, showing excellent conductivity even after modification with organic molecules (Fig. S44 and S45†). In addition, we fabricated an asymmetrical supercapacitor (ASC) solid-state device using ANT-grafted porous carbon (ANT/PC) as a positive electrode, porous carbon (PC) as a negative electrode, and a Whatman filter paper soaked with 1 M H_2SO_4 as a separator. The ASC device demonstrated a specific capacitance of 155 F g^{-1} at 2 A g^{-1} with an energy density of 5.8 W h kg^{-1} at a high-power density of 2010 W kg^{-1} (Fig. S46†), calculated using methods in the literature.^{72–75} Four ASC devices were connected in series, showcasing excellent performance with an LED light-up time of 5 ± 0.8 minutes after charging with a 6 V battery for 2 minutes (Fig. S47†).

To understand the origin of pseudocapacitance in metal-free ANT thin films, we performed pH-dependent electrochemical studies to examine whether the faradaic process follows the interfacial proton-coupled electron transfer (PCET) pathway.^{76–80} The differential pulse voltammogram (DPV) of the ANT/GR electrode with varied pH was recorded in H_2SO_4 solution using 0.1 M KCl as an electrolyte (Fig. 6a). The plot clearly shows the shift in anodic and cathodic potential with respect to pH, illustrating the dependence of the faradaic process on the pH of the solution, a hallmark of PCET



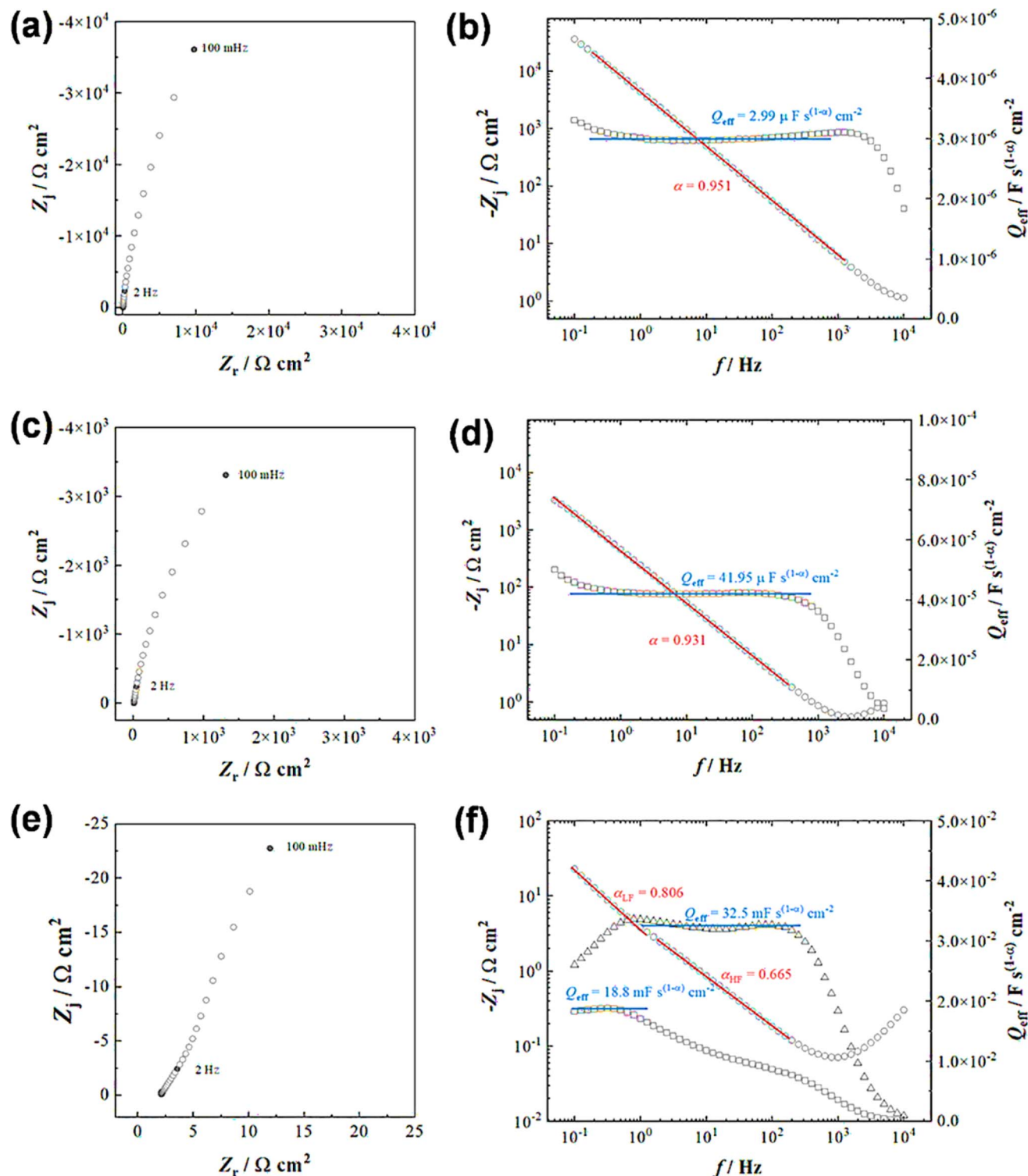


Fig. 5 Electrochemical impedance responses and graphical analysis for the determination of CPE parameters on (a and b) the bare electrode, (c and d) ANT-modified GR, and (e and f) after 10^4 GCD cycles at +0.3 V (vs. Ag/AgCl in 1 M H_2SO_4).

reactions.⁸¹ Next, the reduction potential as a function of pH was observed from the Pourbaix diagram to understand the interfacial proton-coupled electron transfer (PCET) reactions (Fig. 6b). The plot shows a slope of 67.6 ± 3.0 mV per pH (close to 59 mV), suggesting that the process involves concerted 1 H^+ /

1 e^- transfer events. The overall interfacial PCET pathway is illustrated in Fig. 6c. For simplicity, we have considered only a few molecular layers for depiction of the mechanism. The electrochemical charge storage performance of carbon materials functionalized by a few organic molecules using



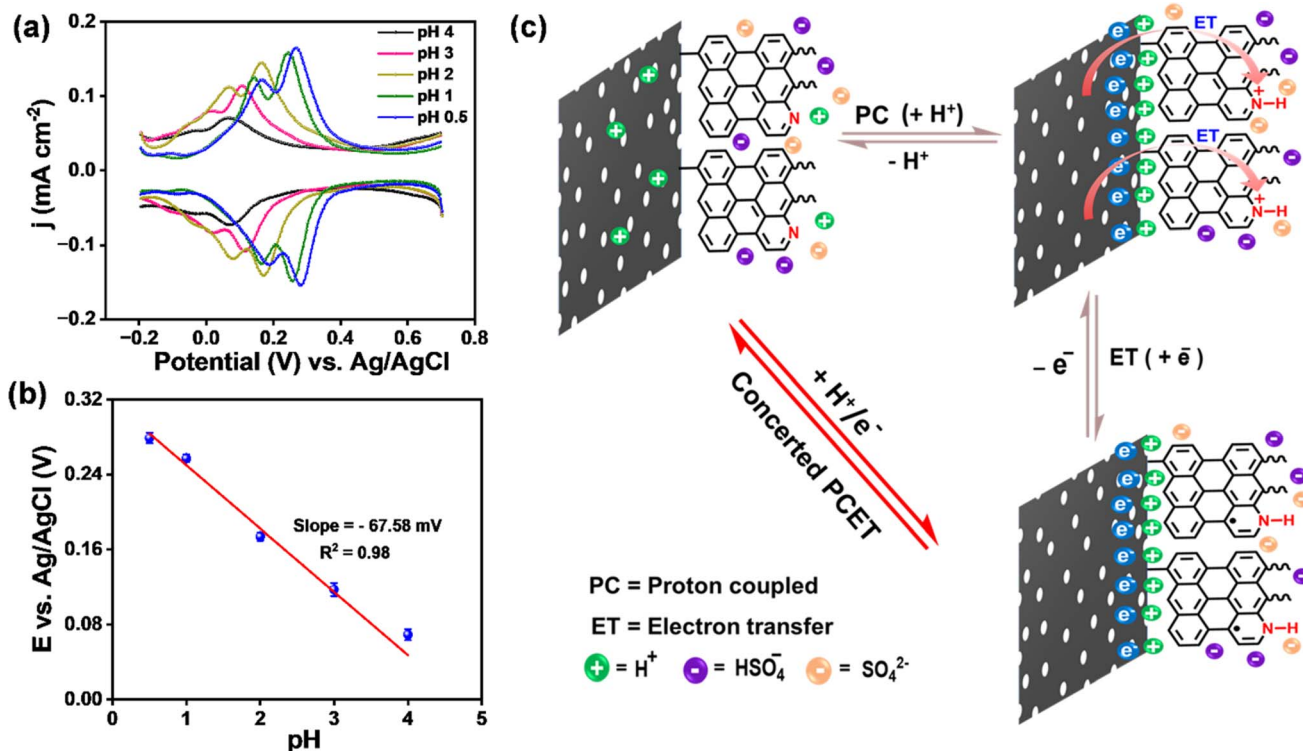


Fig. 6 Understanding the capacitance enhancement in the light of proton-coupled electron transfer mechanism. (a) DPV of the ANT/GR electrode recorded with varying pH of H₂SO₄ solution using 0.1 M KCl as electrolyte. (b) Reduction potential vs. pH plot (from DPV data). (c) Schematic illustration of interfacial PCET pathway to and from different nitrogens present in the ANT/GR electrode.

diazonium chemistry is studied by a few groups, and our results are compared in Table S9.†

Conclusions

The electrochemical grafting method performed on a metal-free platform demonstrates promising potential to further extend the scope of functionalization on a variety of carbon electrodes, including flexible carbon materials and carbon clothes, and can be employed for microfabricated flexible supercapacitor devices. To enhance the young family of organic supercapacitors, we validated low-cost graphite rod modification in nanoscale dimension *via* a versatile electrochemical grafting approach, showing promising opportunities for reusing waste carbon rods for large amounts of energy storage applications. However, the capacitance value of the present work does not meet the demand for practical application, but considering the molecular film thickness, which is ~ 24 nm, and low surface coverage, this value cannot be neglected. Upon increasing the surface coverage and attaching more molecular layers, capacitance can be enhanced. The present work opens new horizons in the field of nanoscale hybrid supercapacitors (rigid to flexible) with baselines for future energy metrics to advance toward commercial implementation.

Data availability

Data is available upon request from the corresponding author.

Author contributions

R. G. and A. M. designed, conducted the experiments, and wrote the manuscript. K. K. and S. K. S. performed computational studies. V. V. performed impedance spectra analysis. P. C. M. conceived the idea, supervised the work, and edited the manuscript. All authors contributed to the discussion and editing of the manuscript.

Conflicts of interest

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper. RG, AM, and PCM have filed a provisional Indian patent application (Application No. 202211060927) lodged with the IIT Kanpur based on the work reported here.

Acknowledgements

R. G. and A. M. thank IIT Kanpur for the senior research fellowship and Institute post-doctoral fellowship (No. PDF-254), respectively. P. C. M. acknowledges the Council of Scientific & Industrial Research (CSIR), New Delhi, for partial financial support, Sanctioned No. 01(3049)/21/EMR-II, Science and Engineering Research Board, New Delhi (Grant No. CRG/2022/005325), IIT Kanpur. S. K. S. acknowledges financial support

from CRG/2023/002936. The authors acknowledge IIT Kanpur for its infrastructure and instrumentation facility.

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